OSRAM SFH 4715B Datasheet

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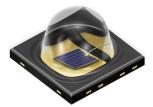




OSLON™ Black



OSLON Black Series (850 nm) - 80°





Applications

- Access Control & Security
- Authentication
- Eye, face and hand tracking

- Factory Automation
- Home & Building Automation
- Medical Lighting

Features

- Package: clear silicone
- ESD: 2 kV acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)
- IR lightsource with high efficiency
- Centroid wavelength 850 nm
- Low thermal resistance



Ordering Information

Туре	Radiant intensity 1)2)	Radiant intensity ¹⁾ typ.	Ordering Code
	l _F = 1000 mA; t _p = 10 ms l _e	I _F = 1000 mA; t _p = 10 ms I _e	
SFH 4715B	500 710 mW/sr	580 mW/sr	Q65113A9877



Maximum Ratings

T _A = 25 °C			
Parameter	Symbol		Values
Operating temperature	T _{op}	min.	-40 °C
	op	max.	125 °C
Storage temperature	T _{stg}	min.	-40 °C
	Stg	max.	125 °C
Junction temperature	T _j	max.	145 °C
Forward current	I _F	min.	20 mA
		max.	2 A
Forward current pulsed	I _{F pulse}	max.	3 A
t _p ≤ 10 ms; D ≤ 0.005	i puloo		
Reverse voltage ³⁾	V _R	max.	5 V
ESD withstand voltage	V _{ESD}	max.	2 kV
acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)	200		

For the forward current and power consumption please see "maximum permissible forward current" diagram. The maximum forward current dimming range shall not be larger than 10.



Characteristics

 $I_{_{\rm F}}$ = 1000 mA; $t_{_{
m p}}$ = 10 ms; $T_{_{
m A}}$ = 25 °C

Parameter	Symbol		Values	
Peak wavelength	$\lambda_{_{peak}}$	typ.	858 nm	
Centroid wavelength	$\lambda_{centroid}$	typ.	850 nm	
Spectral bandwidth at 50% I _{rel.max} (FWHM)	Δλ	typ.	30 nm	
Half angle	φ	typ.	40 °	
Rise time (10% / 90%) I _F = 1000 mA; R _L = 50 Ω	t _r	typ.	12 ns	
Fall time (10% / 90%) I _F = 1000 mA; R _L = 50 Ω	t _r	typ.	12 ns	
Forward voltage 4)	V _F	min.	1.55 V	
		typ. max.	1.85 V	
Forward voltage 4)	V _F	typ.	1.75 V	
I _F = 2A; t _p =100μs		max.	2.1 V	
Forward voltage 4)	V _F	typ.	1.9 V	
$I_{F} = 3A; t_{p} = 100 \mu s$		max.	2.4 V	
Reverse current ³⁾	I _R	typ.	0.01 µA	
$V_{R} = 5 V$		max.	10 µA	
Radiant intensity ¹⁾ $I_{F} = 2A; t_{p} = 100 \mu s$	l _e	typ.	1150 mW/sr	
Total radiant flux ⁵⁾ $I_F = 1A; t_p = 100 \mu s$	Φ_{e}	typ.	1050 mW	
Total radiant flux ⁵⁾ $I_F = 2A; t_p = 100 \mu s$	Φ _e	typ.	2000 mW	
Thermal resistance junction solder point electrical ⁶⁾	R _{thJS elec.}	typ.	2.1 K / W	
with efficiency η_e = 68 %		max.	2.6 K / W	



Brightness Groups

Group	Radiant intensity 1)2)	Radiant intensity ¹⁾²⁾	
	I _F = 1000 mA; t _p = 10 ms	$I_{F} = 1000 \text{ mA}; t_{p} = 10 \text{ ms}$	
	min.	max.	
	l _e	l _e	
DA2	500 mW/sr	560 mW/sr	
DB1	560 mW/sr	630 mW/sr	
DB2	630 mW/sr	710 mW/sr	

Only one group in one packing unit

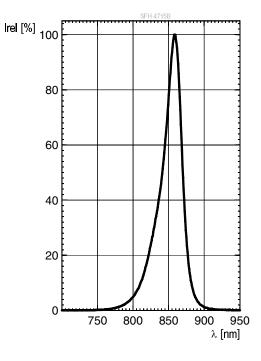
Forward Voltage Groups

Group	Forward voltage ⁴⁾	Forward voltage 4)
	min.	max.
	V _F	V _F



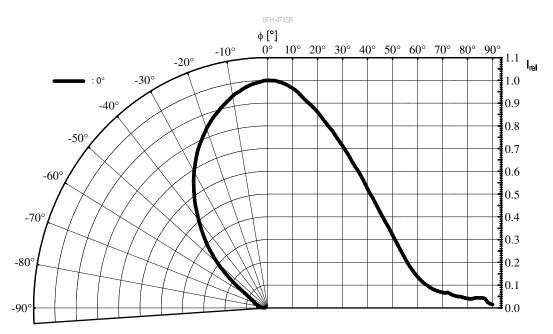
Relative Spectral Emission 7), 8)

 $I_{e,rel} = f(\lambda); I_{F} = 1000 \text{ mA}; t_{p} = 10 \text{ ms}$



Radiation Characteristics ^{7), 8)}

 $I_{e,rel} = f(\phi)$



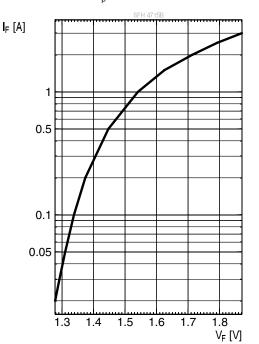


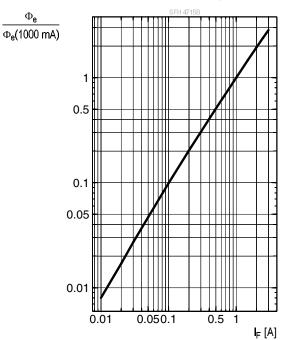
Forward current ^{7), 8)}

 $I_{_{F}}$ = f (V_{_{F}}); single pulse; $t_{_{p}}$ = 100 µs

Relative Total Radiant Flux 7), 8)

 $\Phi_{e}/\Phi_{e}(1000\text{mA}) = f (I_{F})$; single pulse; $t_{p} = 100 \ \mu\text{s}$





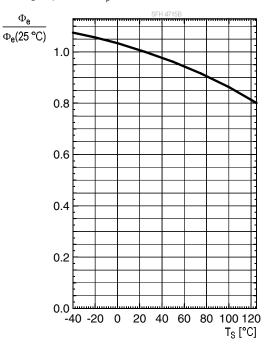


Forward Voltage ⁷) $V_{F, rel} = f(T_S); I_F = 1 A; t_p = 100 \ \mu S$ $\Delta V_F [M]$ 0.04 0.02 0.02 0.00 -0.02 -0.04

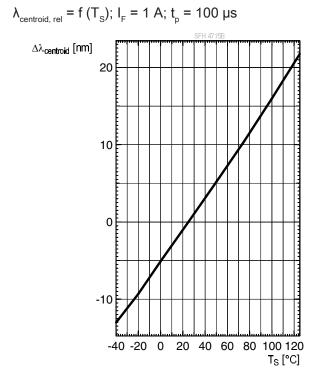
T_S [°C]

Relative Total Radiant Flux⁷⁾

 $\Phi_{e, rel} = f(T_{S}); I_{F} = 1 \text{ A}; t_{p} = 100 \text{ }\mu\text{s}$



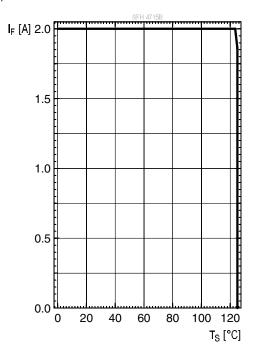
Centroid Wavelength 7)





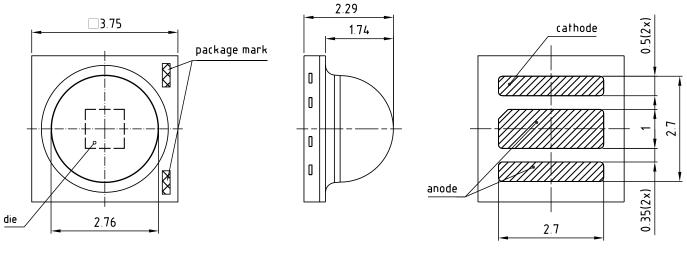
Max. Permissible Forward Current

 $I_F = f(T_S)$





Dimensional Drawing ⁹⁾



general tolerance ± 0.1 lead finish Au

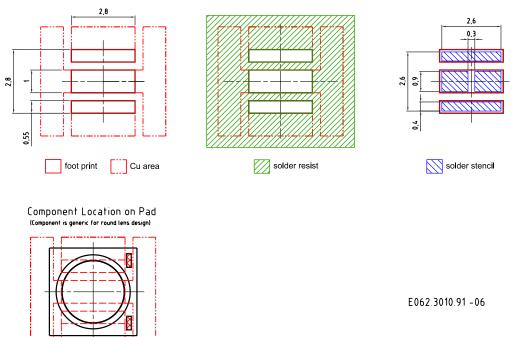
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Further Information:

Approximate Weight:	32.0 mg
Package marking:	Cathode



Recommended Solder Pad ⁹⁾

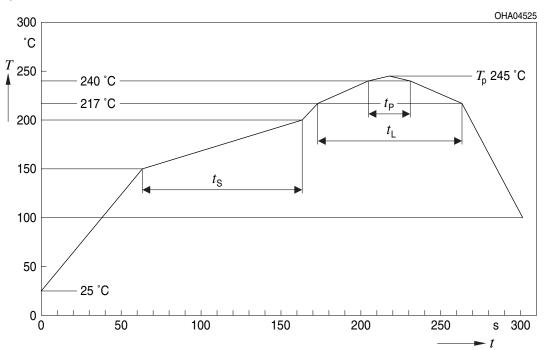


For superior solder joint connectivity results we recommend soldering under standard nitrogen atmosphere. Package not suitable for ultra sonic cleaning.



Reflow Soldering Profile





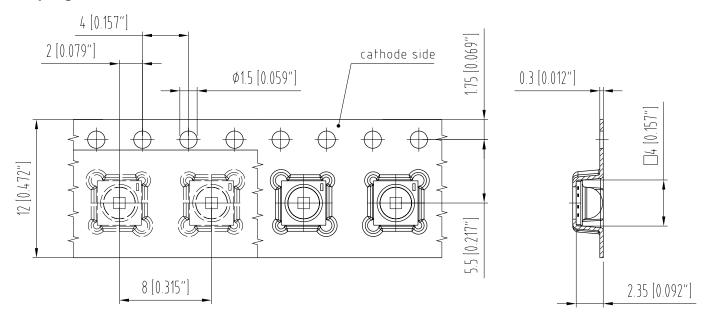
Profile Feature	Symbol	Pb	b-Free (SnAgCu) Assembly		Unit
		Minimum	Recommendation	Maximum	
Ramp-up rate to preheat [•]) 25 °C to 150 °C			2	3	K/s
Time t _s T _{Smin} to T _{Smax}	t _s	60	100	120	S
Ramp-up rate to peak ^{*)} T_{smax} to T_{P}			2	3	K/s
Liquidus temperature	TL		217		°C
Time above liquidus temperature	t		80	100	S
Peak temperature	T _P		245	260	°C
Time within 5 °C of the specified peak temperature T_{p} - 5 K	t _P	10	20	30	S
Ramp-down rate* T _P to 100 °C			3	6	K/s
Time 25 °C to T _P				480	S

All temperatures refer to the center of the package, measured on the top of the component

* slope calculation DT/Dt: Dt max. 5 s; fulfillment for the whole T-range



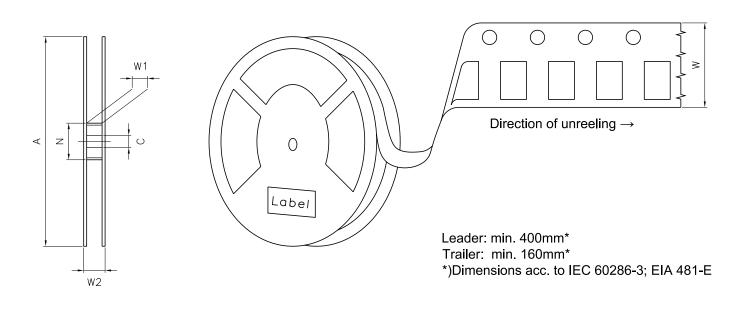
Taping ⁹⁾



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Tape and Reel ¹⁰⁾

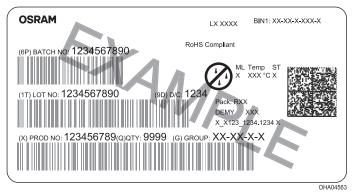


Reel Dimensions

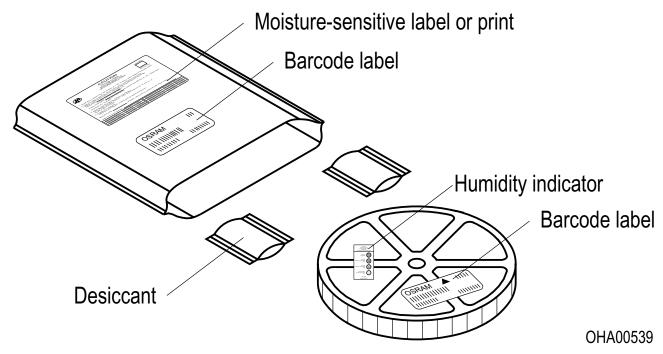
А	W	N _{min}	W ₁	$W_{2\text{max}}$	Pieces per PU
180 mm	12 + 0.3 / - 0.1 mm	60 mm	12.4 + 2 mm	18.4 mm	600



Barcode-Product-Label (BPL)



Dry Packing Process and Materials ⁹⁾



Moisture-sensitive product is packed in a dry bag containing desiccant and a humidity card according JEDEC-STD-033.



Notes

The evaluation of eye safety occurs according to the standard IEC 62471:2006 (photo biological safety of lamps and lamp systems). Within the risk grouping system of this IEC standard, the device specified in this data sheet falls into **exempt risk group - Exempt**.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

For further application related information please visit https://ams-osram.com/support/application-notes



Disclaimer

Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version on our website.

Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Product and functional safety devices/applications or medical devices/applications

Our components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

Our products are not qualified at module and system level for such application.

In case buyer – or customer supplied by buyer – considers using our components in product safety devices/ applications or medical devices/applications, buyer and/or customer has to inform our local sales partner immediately and we and buyer and /or customer will analyze and coordinate the customer-specific request between us and buyer and/or customer.



Glossary

- ¹⁾ **Radiant intensity:** Measured at a solid angle of Ω = 0.01 sr
- ²⁾ **Brightness:** The brightness values are measured with a tolerance of $\pm 11\%$.
- ³⁾ **Reverse Operation:** This product is intended to be operated applying a forward current within the specified range. Applying any continuous reverse bias or forward bias below the voltage range of light emission shall be avoided because it may cause migration which can change the electro-optical characteristics or damage the LED.
- ⁴⁾ **Forward Voltage:** The forward voltages are measured with a tolerance of ±0.1 V.
- ⁵⁾ **Total radiant flux:** Measured with integrating sphere.
- ⁶⁾ **Thermal resistance:** junction soldering point, of the device only, mounted on an ideal heatsink (e.g. metal block)
- ⁷⁾ Typical Values: Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- ⁸⁾ **Testing temperature:** TA = 25°C (unless otherwise specified)
- ⁹⁾ **Tolerance of Measure:** Unless otherwise noted in drawing, tolerances are specified with ±0.1 and dimensions are specified in mm.
- ¹⁰⁾ **Tape and Reel:** All dimensions and tolerances are specified acc. IEC 60286-3 and specified in mm.



Revision History

Version	Date	Change
1.0	2025-05-19	Product Image Characteristics Electro - Optical Characteristics (Diagrams) Derating (Diagrams)



EU RoHS and China RoHS compliant product 此产品符合欧盟 RoHS 指令的要求; 按照中国的相关法规和标准, 不含有毒有害物质或元素。

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